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AEC-0200

DATE:

ROHS+HS

APPROVAL SPECIFICATION

COMPLIANT PRODUCT NAME: SMD power inductor YOUR PART NO.: AMPSM252012BE-21 series OUR PART NO .: VERSION: V1.0 RECEPTION THE SPECIFICATION HAS BEEN ACCEPTED. DATE: **COMPANY:** CFMD CHKD RCVD

MANUFACTURING NAME

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CATALOG

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Component SPEC Version Record

Rev.	Effective Date	Changed Contents	Change Reasons	Approved By
/1.0	2019.11.08	New released	/	Charles
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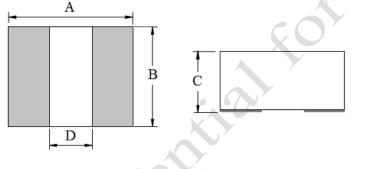
Recommended Land Pattern

1. Scope

This specification applies to the AMPSM252012BE series of SMD power inductor.

2. Product Identification

AMPSM 252012 BE <u>2R2</u> ④ <u>M</u> ⑤ <u>21</u> - <u>LF</u> ⑥ ⑦ 3 (1) (2)crosse ① Product Symbol. (Automotive electronics products) ② Product dimensions. ③ Special process code. ④ Inductance Value: (R33: 0.33uH 2R2: 2.2uH 100:10uH) (5) Inductance Tolerance: (M: $\pm 20\%$; N: $\pm 30\%$) 6 Process code \bigcirc Lead free product. 3. Appearance and Dimensions



Note: Gray area is electrode

 Dimensions in mm

 A
 B
 C
 D
 f
 g
 h

 2.50 ±0.20
 2.00 ±0.20
 1.20Max.
 0.70Typ.
 0.60Typ.
 2.70 Typ.
 2.10 Typ.



x Ø

4. Testing Conditions

Unless otherwise specified, the standard conditions for measurement/test as: Ambient Temperature : 5 to 35°C Relative Humidity: 25 to 85% RH Atmospheric Pressure: 86 to 106 kPa

If any doubt on the results, measurements/tests should be made within the following limits: Ambient Temperature : 25 ± 1 °C Relative Humidity: 60 to 70% RH Atmospheric Pressure: 86 to 106 kPa

5. Electrical Characteristics And Test Instruments

Miana anta Daut Na	Inductance	L0 (uH)		Isat	Isat	Irms	Irms
Microgate Part No.	· · ·			(A) Max.	(A) Typ.	(A) Max.	(A) Typ.
AMPSM252012BER15M21-LF	0.15±20%	11	6	9.0	10.0	7.3	9.8
AMPSM252012BER22M21-LF	0.22±20%	13	11	8.0	9.0	6.7	8.5
AMPSM252012BER33M21-LF	0.33±20%	20	16	6.4	7.5	4.8	5.4
AMPSM252012BER47M21-LF	0.47±20%	26	21	5.6	6.5	4.0	4.7
AMPSM252012BER68M21-LF	0.68±20%	31	26	4.8	5.4	3.6	4.0
AMPSM252012BE1R0M21-LF	1.0±20%	41	35	4.2	4.8	3.4	3.8
AMPSM252012BE1R5M21-LF	1.5±20%	60	50	3.3	3.9	2.7	3.1
AMPSM252012BE2R2M21-LF	2.2±20%	87	73	3.0	3.5	2.2	2.4
AMPSM252012BE3R3M21-LF	3.3±20%	140	118	2.3	2.7	2.0	2.2
AMPSM252012BE4R7M21-LF	4.7±20%	200	165	2.0	2.2	1.4	1.7

Test instruments and remarks

* All test data is referenced to 25° C ambient.

* L test by CHROMA 3302 meter or equivalent

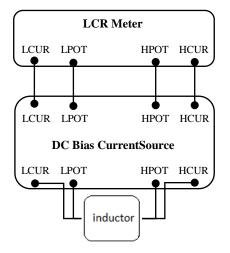
* DCR test by Tonghui TH2516B meter or equivalent

* CHROMA 3302 and 1320 meter for IDC;

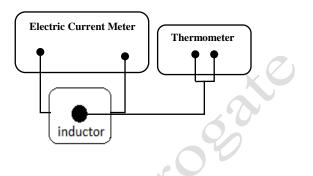
- * Isat: DC current (A) that will cause L0 to drop approximately 30%.
- * Irms: DC current (A) that will cause an approximate ΔT of 40 °C.
- * Operating temperature: -55° C to $+155^{\circ}$ C (Including self temperature rise).

* The part temperature (ambient + temp rise) should not exceed 155° C under worse case operating conditions. Circuit design, component placement, PCB trace size and thickness, airflow and other cooling provision all affect the part temperature. Part temperature should be verified in the end application.

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Isat test schematic diagram



Irms test schematic diagram

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6. Reliability

No.	Item	Requirements	Test Methods and Remarks	Reference	Sample Size
1	Solderability	(1) No physical damage.(2) Terminal area must have 95% min. solder coverage.	 Temperature:245±5°C, flux 5-10 s. Sample immersion tin furnace 5 ±0.5s. Immersed and in and out of speed: 25 ± 6mm/s. 	AEC-Q200 (J-STD-002)	15
2	Resistance to Soldering Heat	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 ①The peak temperature: 260+5/-0°C. ②Reflow:3times. ③Temperature curve is as below: 265℃ 265℃ Max. Ramp Up Rate=3℃/s 30 sec min. Rate=-6℃/s 200℃ 200℃ 200℃ 5℃ 150℃ 5℃ 150℃ 5℃ 150℃ 5℃ 150℃ 150 ecc. 150 e	AEC-Q200 (MIL-STD-202 Method 210)	30
3	High Temperature Storage	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 ①Temperature: 155±2°C. ②Time : 1000 hours. ③Measurement at 24±4 hours after test conclusion. Temp High temperature 155°C Room Temp 0 1000H	AEC-Q200 (MIL-STD -202 Method 108)	77
4	Temperature Cycling	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 ①1000 cycles (-40°C to +155°C). ②30min maximum dwell time at each temperature extreme. 1 min. maximum transition time. ③Measurement at 24±4 hours after test conclusion. 	AEC-Q200 (JESD22-A104)	77
5	Resistance to Solvents	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 Prepare solvent (isopropyl alcohol: kerosene: ethylbenzene =4:9:3 volume) Specimen be completely immersed in solvent for 3+0.5/-0min Brush dipped in solution until wetted and brush part 10 strokes . Repeat 2 more times, Air blow dry. Inspect at 3x magnifier for marking and 10x for part damage. Note: Add Aqueous wash chemical. OKEM Clean or equivalent. Do not use banned solvents. 	AEC-Q200 (MIL-STD-202 Method 215)	5



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No.	Item	Requirements	Test Methods and Remarks	Reference	Sample Size
6	ESD	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 ①3 times in each of terminals and top side of component. ②Direct contact discharge: 1C(1000V(DC) to <2000V(DC)) 	AEC-Q200 (AEC-Q200- 002)	15
7	Biased Humidity	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 ①1000 hours, 85 °C/85% RH. ②Unpowered. ③Measurement at 24±4 hours after test conclusion. 	AEC-Q200 (MIL-STD -202 Method 103)	77
8	Terminal Strength	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 ①The test samples shall be soldered to the board. ②17.64N, 60s BUT Radius 0.5mm BUT Reduce 0.5mm BUT Reduce 0.5mm Press tools Shear force 	AEC-Q200 (AEC-Q200-006)	30
9	Board Flex	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 (1) Part mounted on a 100mm*40mm FR4 PCB board, which is 1.6±0.2 mm thick and as a Layer-thickness 35 µm ± 10 µm. (2) Bending speed is 1mm/s. (3) Keeping the P.C Board 2 mm minimum for 60 seconds. 	AEC-Q200 (AEC-Q200-005)	30
10	Vibration	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 Frequency range : 10~2000Hz. Amplitude: 1.5mm, 5g. Sweep time and duration: 10~2000~10Hz for 20 minutes. Each four hours in X,Y,Z direction, 12 hours in total. 	AEC-Q200 (MIL-STD-202 Method 204)	30
11	Mechanical Shock	 (1) No physical damage. (2) ΔL0/L0 ≤10% 	 Peak acceleration:100G/S Duration of pulse:6ms 3times in each of 6(±X, ±Y, ±Z) axes. 	AEC-Q200 (MIL-STD-202 Method 213)	30



No.	Item	Requirements	Test Methods and Remarks	Reference	Sample Size
12	Loading at High Temperature	AEC-Q200 (MIL-PRF-27)	77		
13	Physical Dimension	According to specification	Verify physical dimensions to the applicable device detail specification.	AEC-Q200 (JESD22-B100)	30
14	Electrical Characterization	AEC-Q200 (User Spec.)	77		
*All a	above experimer	nts items need 3 Lot., samp	le size is as specified in the table above.		
*Sam	ple size standard	t is from AEC-Q200 : qual	ification sample size requirements.		



7. Recommended Soldering Conditions

Peak 260°C max. 260°C ∙5°C Max. Ramp Down Rate=-6°C/s 30 sec. max. Max. Ramp Up Rate=3 °C/s 217°C 60~150 sec. Temperature 200°C 150℃ 60~180 sec. 25℃ Time 25° C to Peak = 8 min max. Time

(1) Reflow soldering conditions

*Above reflow soldering curve is from J-STD-020D.

(2) Iron soldering

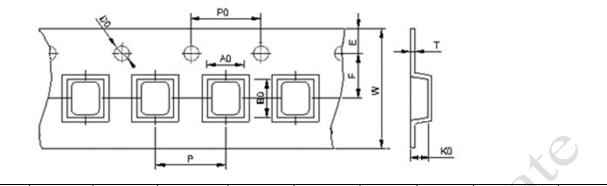
The following conditions must be strictly followed when using a soldering iron.

Pre-heating	150°C 1 minute
Tip temperature	350°C max
Soldering iron output	30w max
End of soldering iron	ф1mm max
Soldering time	3 seconds max



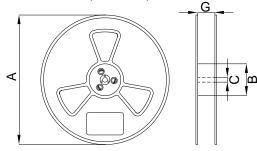
8. Package Information

(1) Dimension of tape (Unit: mm)



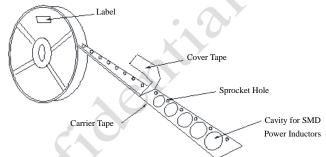
W	A0	B0	K0	Е	F	Р	P0	D0	Т
8.0±0.1	2.50±0.10	2.95±0.10	1.4±0.1	1.75±0.1	3.5±0.1	4.0±0.1	4.0±0.1	1.5+0.1/-0.0	0.18±0.02
(2) Dimension of reel (Unit: mm)									

(2) Dimension of reel (Unit: mm)



Dimension
178±2
58±2
13.5±0.2
9.0±0.5

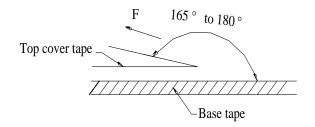
(3) Taping figure and drawing direction



- (4) Packaging quantities: 2000PCS/Reel.
- (5) Peeling strength of cover tape:

The peel force of top cover tape shall be between 0.10N to 1.0N

*the peel force standard is from EIA-481-D



Room Temp.	Room Humidity	Room aim	Peel Speed
(°C)	(%)	(hpa)	mm/min
5-35	45-85	860-1060	300

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9. Products Storage

(1) Storage period

Products which inspected in MICROGATE over 12 months ago should be examined and used, which can be confirmed with inspection No. marked on the container. Solderability should be checked if this period is exceeded.

(2) Storage conditions

Products should be storage in the warehouse on the following conditions: Temperature: $-10 \sim + 35$ °C Humidity: Less than 70% relative and humidity No rapid change on temperature and humidity.

- (3) Don't keep products in corrosive gases such as sulfur, chlorine gas or acid, or it may cause oxidization of electrode, resulting in poor solderability.
- (4) Products should be storage on the palette for the prevention of the influence from humidity, dust and so on.
- (5) Products should be storage in the warehouse without heat shock, vibration, direct sunlight and so on.
- (6) Products should be storage under the airtight packaged condition.

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